

Output Stages

- Power amplifier classification
- Class A amplifier circuits
- Class A Power conversion efficiency
- Class B amplifier circuits
- Class B Power conversion efficiency
- Class AB amplifier circuits
- Class AB Power conversion efficiency

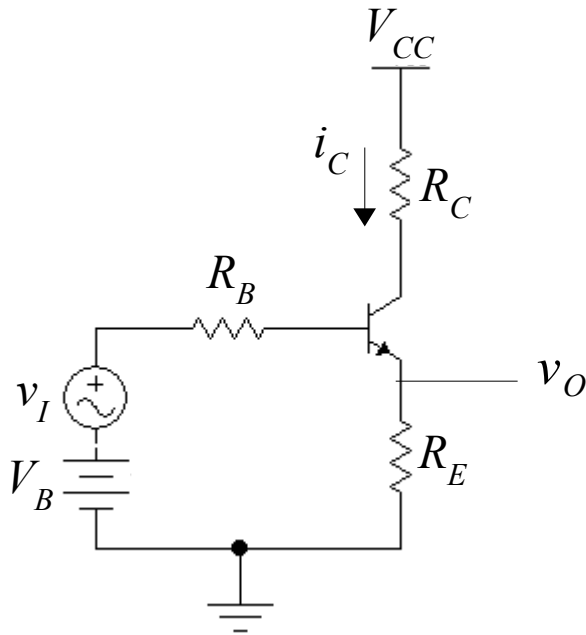
Output Stage Functions

- ◆ Provide amplifier with low output resistance
- ◆ Handle large signals with low THD
- ◆ Deliver power to the load efficiently
- ◆ Output stages are classified according to the i_C waveform due to input v_I waveform

Amplifier Classifications

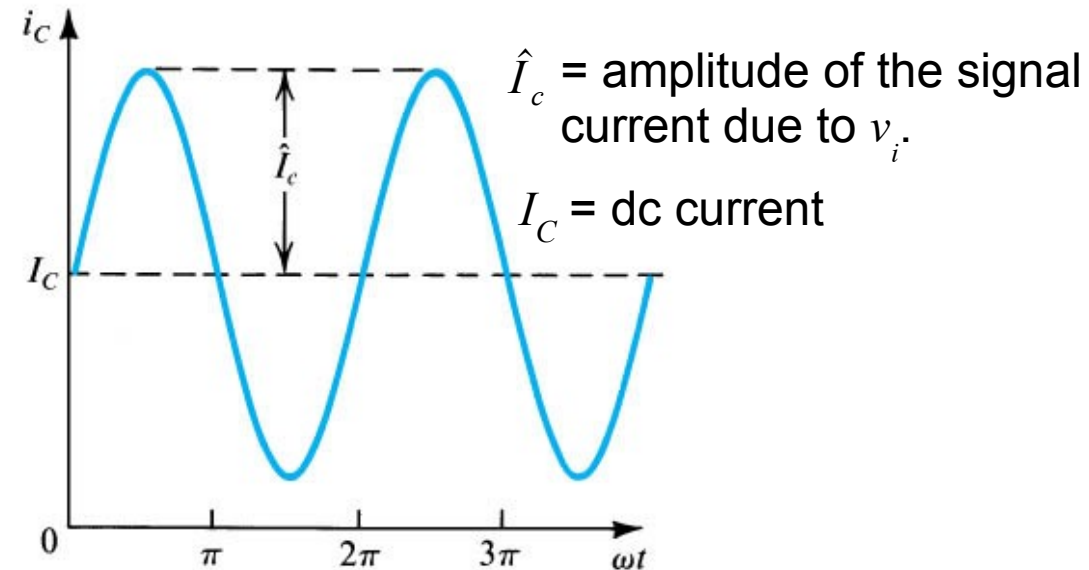
Class A amplifier – amplifier BJT conducts for entire v_I cycle. For all v_I s.t.

$$v_I + V_B \geq 0.7 V \quad \text{where } V_B > \max(v_I) + 0.7 V$$



Transistor cut off ($i_C = 0$) if:

$$v_I + V_B < 0.7 V$$

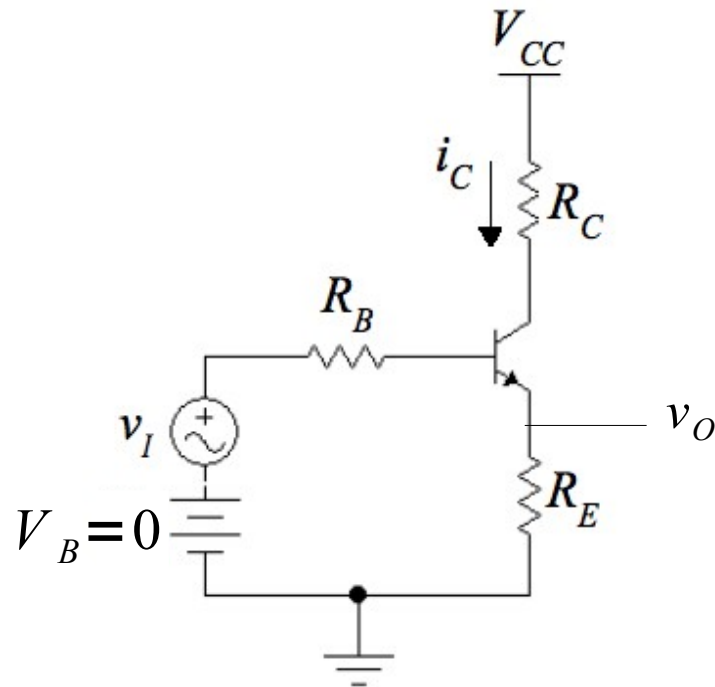


NOTE: when $v_I = 0$, $i_C = I_C$

Amplifier Classifications - cont.

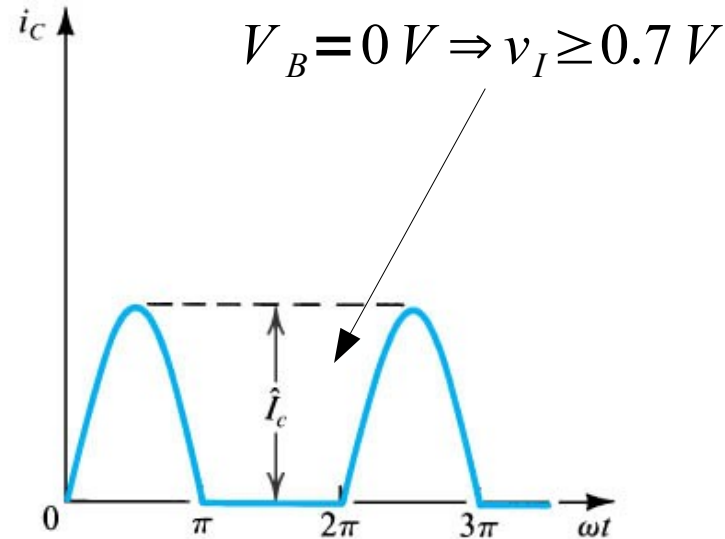
Class B – Amplifier BJT conducts positive-half of v_I cycle.

Amp BJT conducts for all v_I s.t.:



Transistor cut off ($i_C = 0$) if:

$$v_I + V_B < 0.7 V$$



NOTE: 1. when $v_I < 0.7V$, $i_C = 0$

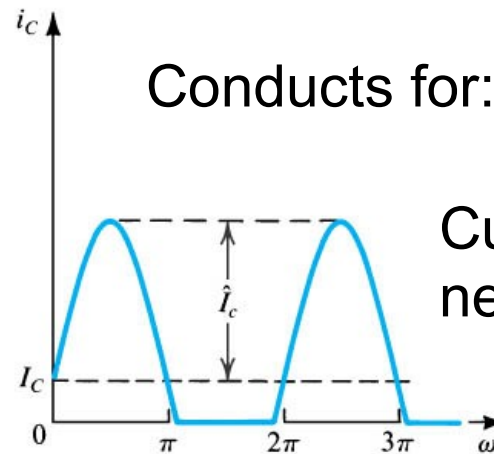
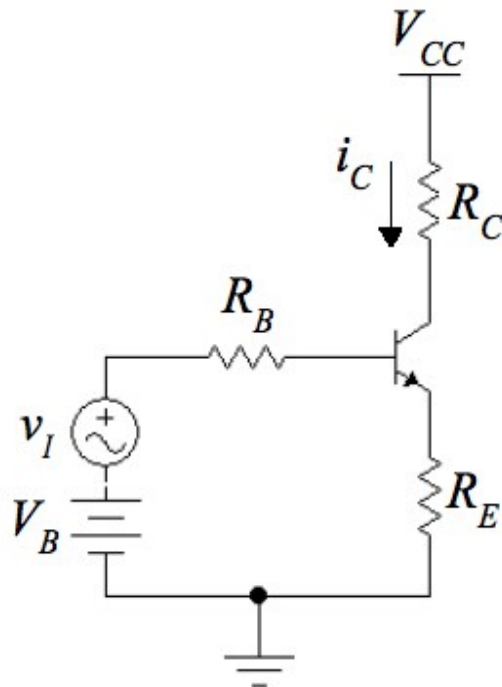
2. A 2nd class B BJT (PNP) is needed to conduct for the negative v_I cycle.

Amplifier Classifications - cont.

Class AB – Amplifier BJT conducts for positive v_I swing + part of negative v_I swing s.t.:

$$v_I + V_B \geq 0.7V \quad \text{where } 0 < V_B < \max(v_I) + 0.7V$$

Conducts for: $v_I \geq 0.7 - V_B$



Cut-off for rest of negative v_I swing:

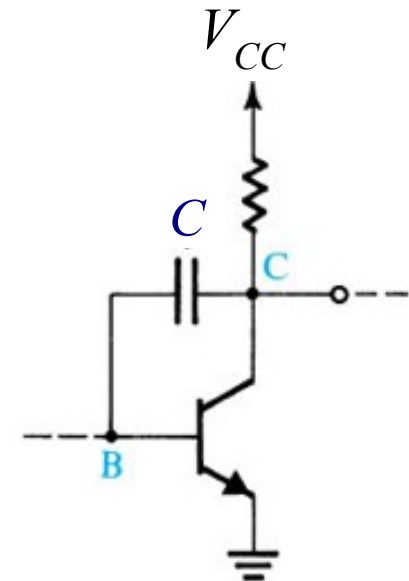
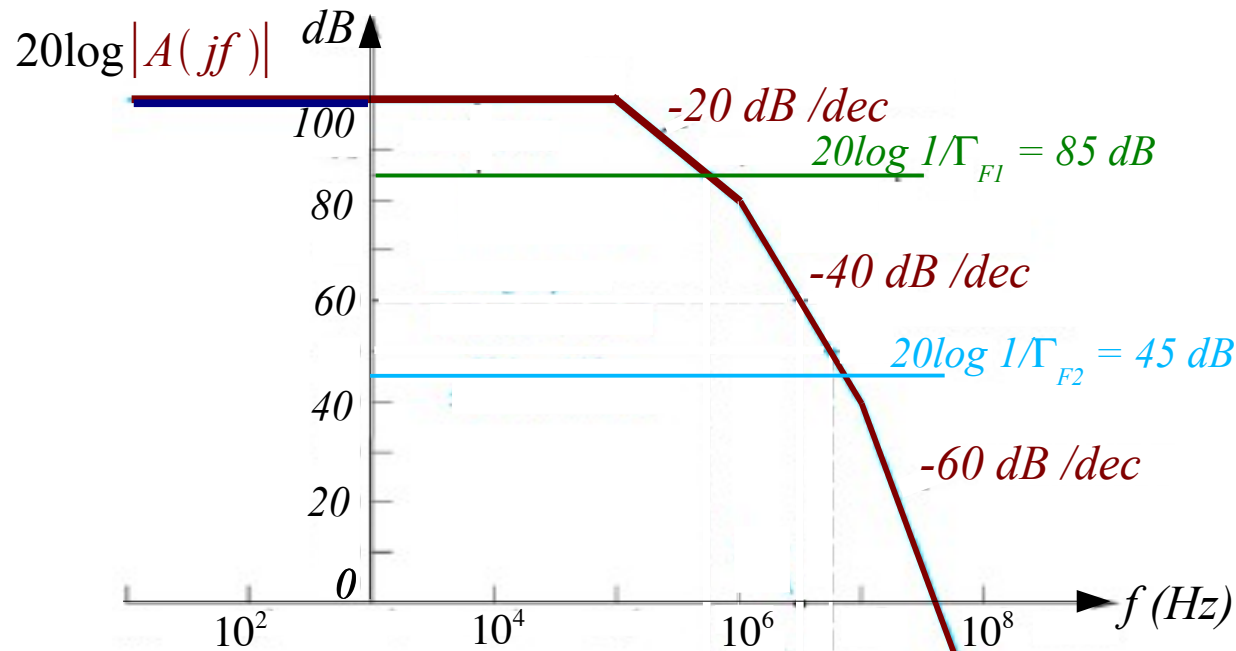
Transistor cut-off ($i_C = 0$) if:

$$v_I + V_B < 0.7V$$

NOTE: 1. when $v_I = 0$, $i_C = I_C$

2. A 2nd class AB BJT (PNP) is needed to conduct for interval slightly larger than the negative v_I cycle.

Quick Review

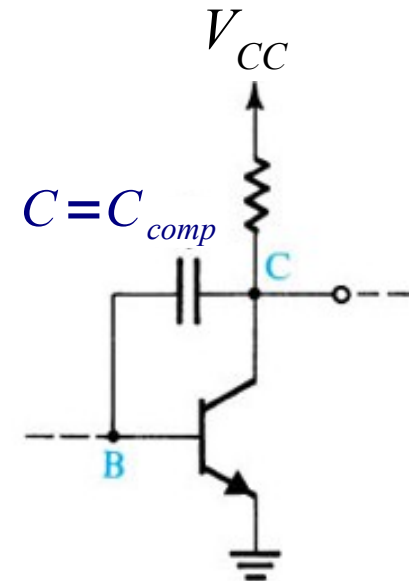
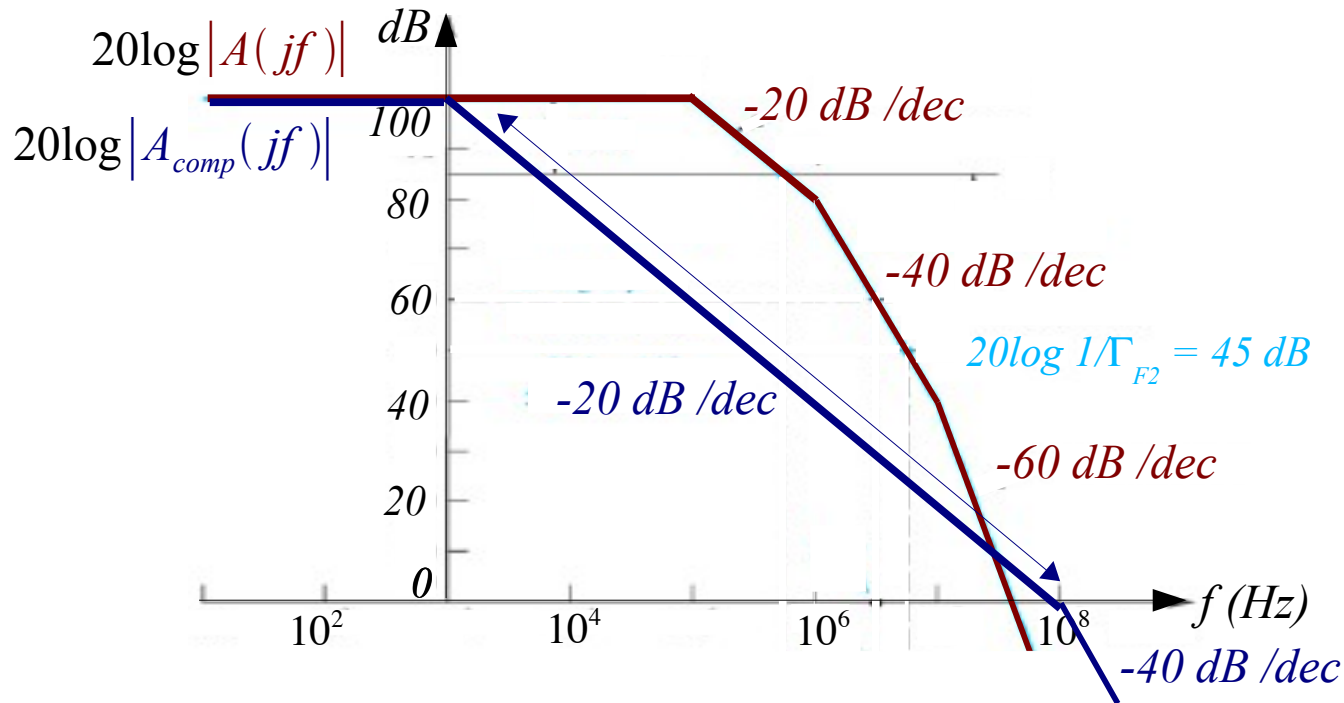


$$A(jf) = \frac{10^5}{(1 + jf/10^5)(1 + jf/10^6)(1 + jf/10^7)}$$

What is the purpose of capacitor “C”?

What does it do the pole locations and its impact on stability?

Quick Review



$$A(jf) = \frac{10^5}{(1 + jf/10^5)(1 + jf/10^6)(1 + jf/10^7)}$$

$$A_{comp}(jf) \approx \frac{10^5}{(1 + jf/10^3)(1 + jf/10^8)(1 + jf/10^7)}$$

Quick Review

1. What is the BJT basic output stage circuit?
2. **Class A amplifier:**
 - What is its characteristic performance?
 - Advantage?
 - Disadvantage?
3. **Class B amplifier:**
 - What is its characteristic performance?
 - Advantage?
 - Disadvantage?
4. **Class AB amplifier:**
 - What is its characteristic performance?
 - Advantage?
 - Disadvantage?

Quick Review

1. What is the BJT basic output stage circuit? **Emitter follower.**
 2. **Class A amplifier:**
What is its characteristic performance? **Conducts over entire v_i cycle.**
Advantage? **Low THD** except when signal amplitude is large.
Disadvantage? **Conducts current and dissipates power when $v_i = 0$.**
 3. **Class B amplifier:**
What is its characteristic performance? **Conducts over $1/2 v_i$ cycle.**
Advantage? **High THD** even when signal amplitude is small.
Disadvantage? **No power dissipated when $v_i = 0$.**
 4. **Class AB amplifier:**
What is its characteristic performance? **Conducts over $>1/2 v_i$ cycle.**
Advantage? **Reduced THD** over Class B.
Disadvantage? **Increased power dissipation** over Class A.
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Class A Power Amplifier Design

Used as op amp output stage and some audio output power amps.

Basic considerations for low (audio) frequency operation.

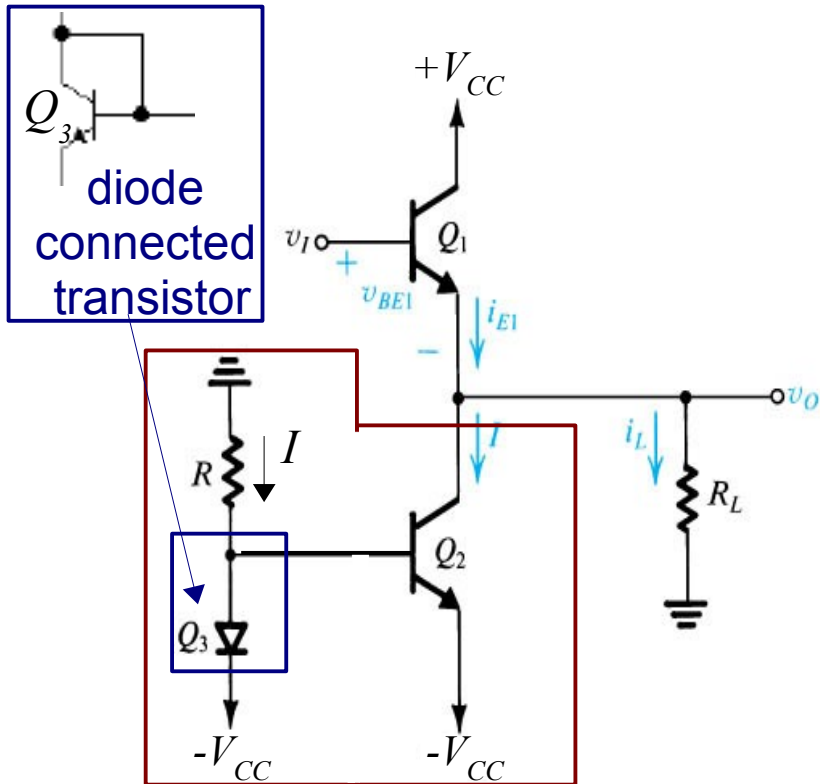
1. Power usually delivered to a low impedance load.
2. Signal usually has little, preferably no dc content.
3. May have low frequency content, as low as 20 Hz .

Emitter follower circuit has best power transfer efficiency, since its output impedance is low. As a bonus, its input impedance is relatively high.

Principal advantage – lower distortion than Class B & AB.

Principal disadvantage – lower power efficiency than Class B & AB.

Current Biased Class A Emitter Follower



current mirror

A current mirror establishes the bias current " I ".

$$i_L = i_{E1} - I$$

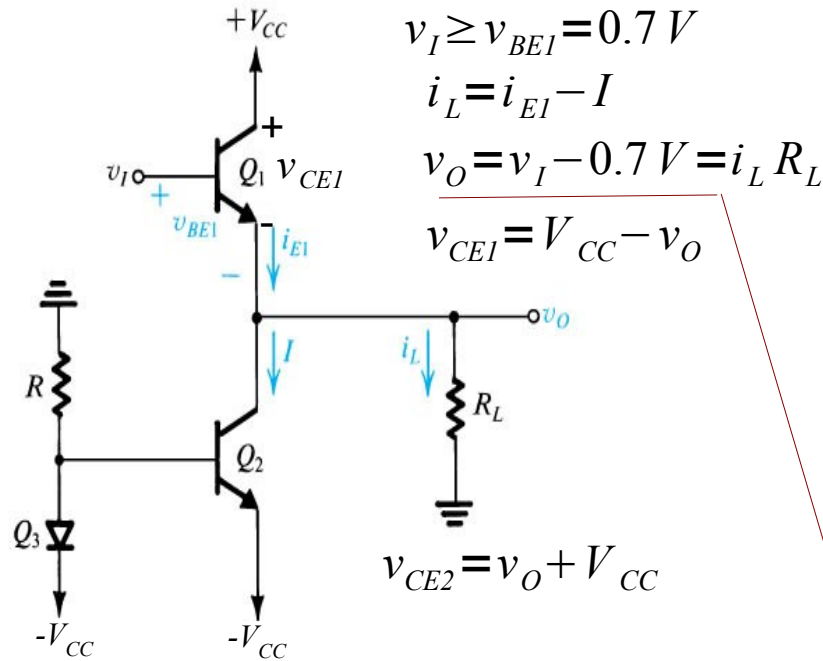
To operate reliably,

1. Q_1 and Q_2 must be forward active.
2. Current Mirror Q_3 and Q_2 need to be matched as well as possible and be at the same ambient temperature.



Class A Amplifier Analysis

Consider the case when $v_I \geq v_{BE1} = 0.7V$ (pos. swing of v_I):



if $v_{CE1} < V_{CE1-sat} \Rightarrow Q_1 \text{ sat.}$

For $Q1 \neq \text{sat:}$ $v_{CE1} > V_{CE1-sat}$

$$v_{CE1} = V_{CC} - v_O > V_{CE1-sat}$$

$$-v_O > -V_{CC} + V_{CE1-sat}$$

$$v_O < V_{CC} - V_{CE1-sat} \Rightarrow v_{O-max} = V_{CC} - V_{CE1-sat}$$

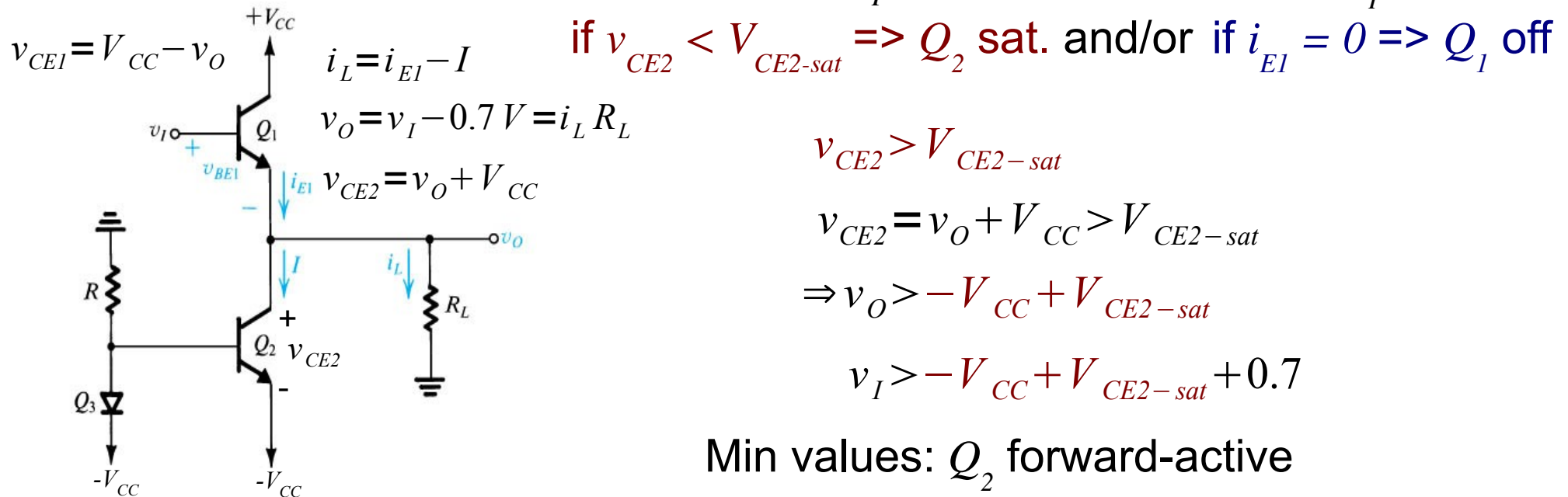
Max values: $Q_1 \neq \text{sat.}$

$$v_O < v_{O-max} = V_{CC} - V_{CE1-sat}$$

$$v_I < v_{I-max} = V_{CC} - V_{CE1-sat} + 0.7V$$

Class A Amplifier Analysis - cont.

Consider the case where $v_I < 0.7 V$ (neg. swing of v_I):



$$v_I < 0.7 V$$

$$v_O = v_I - 0.7 \quad \& \quad v_O = i_L R_L$$

$$v_{CE2} = v_O + V_{CC} = v_I - 0.7 + V_{CC}$$

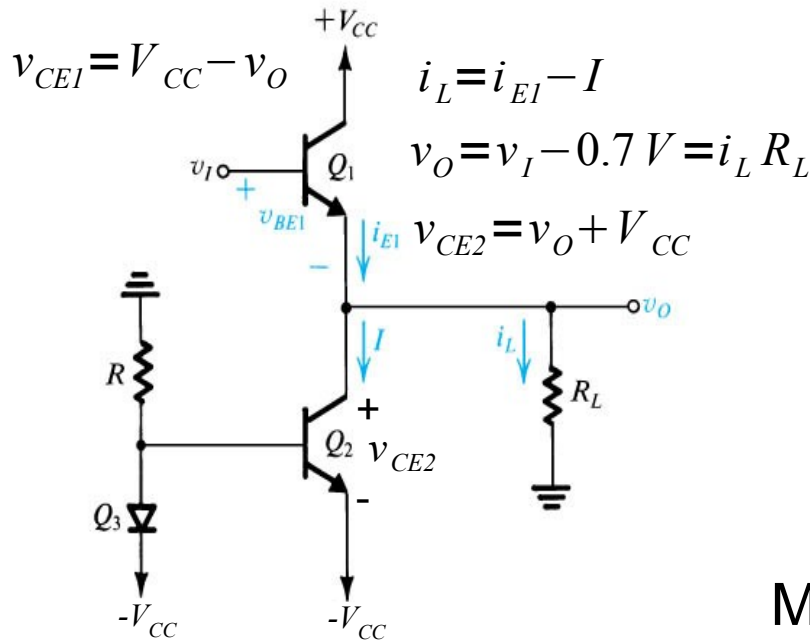
$$v_O > v_{O-min} = -V_{CC} + V_{CE2-sat}$$

$$v_I > v_{I-min} = -V_{CC} + V_{CE2-sat} + 0.7 V$$



Class A Amplifier Analysis - cont.

Consider the case where $v_I < 0.7 V$ (neg. swing of v_I):



if $i_{EI} = 0 \Rightarrow Q_1$ off
 $i_{EI} = i_L + I > 0$
 $i_L = \frac{v_O}{R_L} > -I$
 $v_O > -I R_L$
 $v_I > -I R_L + 0.7 V$

From previous slide

$$v_O > -V_{CC} + V_{CE2-sat}$$

$$v_I > -V_{CC} + V_{CE2-sat} + 0.7$$

Min values: Q_1 and Q_2 forward-active

$$v_O > v_{O-min} = \max \{ -I R_L, -V_{CC} + V_{CE2-sat} \}$$

$$v_I > v_{I-min} = \max \{ -I R_L + 0.7 V, -V_{CC} + V_{CE2-sat} + 0.7 V \}$$

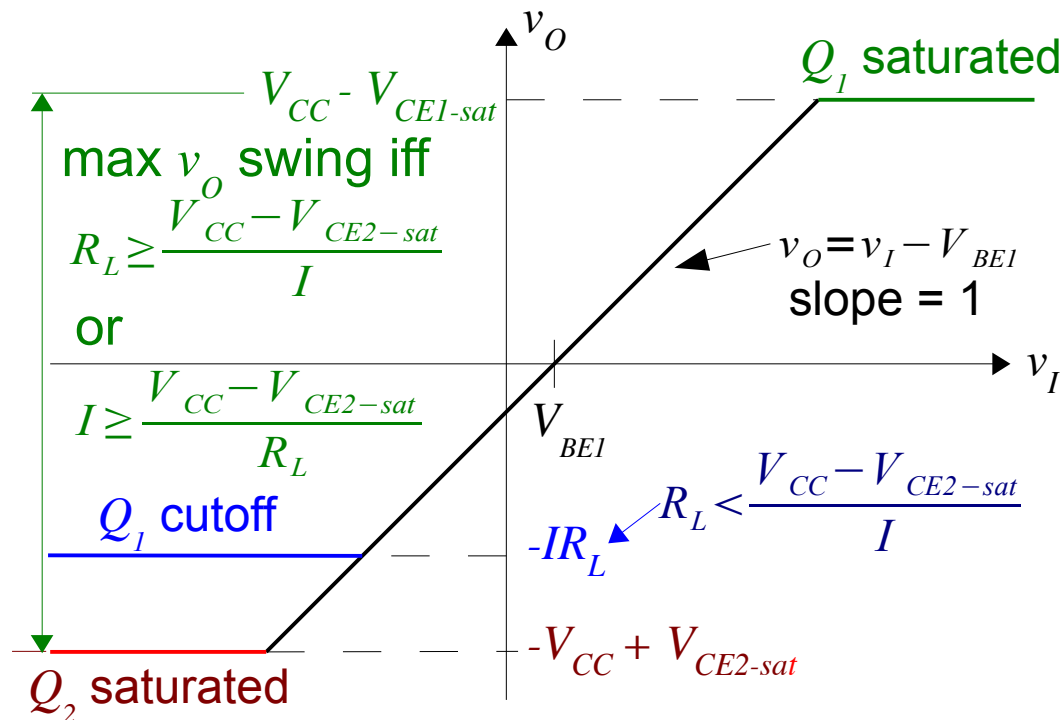
NOTE: max means least negative

$$v_I < 0.7 V$$

$$v_O = v_I - 0.7 \text{ \& } v_O = i_L R_L$$

$$v_{CE2} = v_O + V_{CC} = v_I - 0.7 + V_{CC}$$

Class A Amplifier VTC – Plot



Bias current I & R_L set limits on negative $v_O = v_{O-min}$ swing

Iff $-IR_L > -(V_{CC} - V_{CE2-sat})$

$$v_O > v_{O-min} = -IR_L \Rightarrow$$

$$R_L < \frac{V_{CC} - V_{CE2-sat}}{I}$$

If $-IR_L < -(V_{CC} - V_{CE2-sat})$

$$v_O > v_{O-min} = -V_{CC} + V_{CE2-sat} \Rightarrow$$

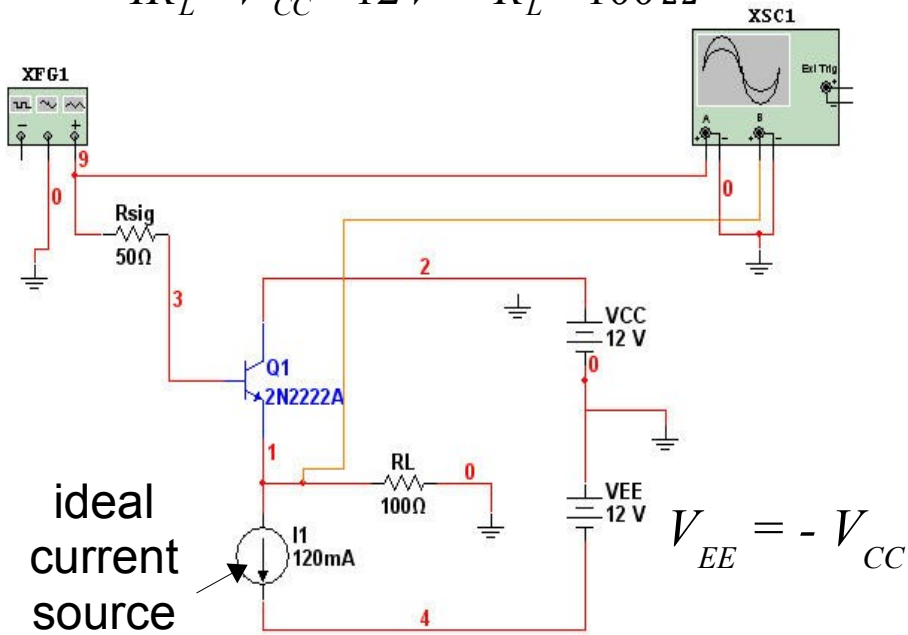
$$R_L > \frac{V_{CC} - V_{CE2-sat}}{I}$$

$$v_O = v_I - 0.7 \quad \text{where} \quad \max\{-IR_L, -(V_{CC} - V_{CE2-sat})\} < v_O < V_{CC} - V_{CE1-sat}$$

Class A Stage VTC Simulation

$$I = 120 \text{ mA}$$

$$IR_L = V_{CC} = 12 \text{ V} \Rightarrow R_L = 100 \Omega$$



ideal
current
source
i.e. no
 Q_2

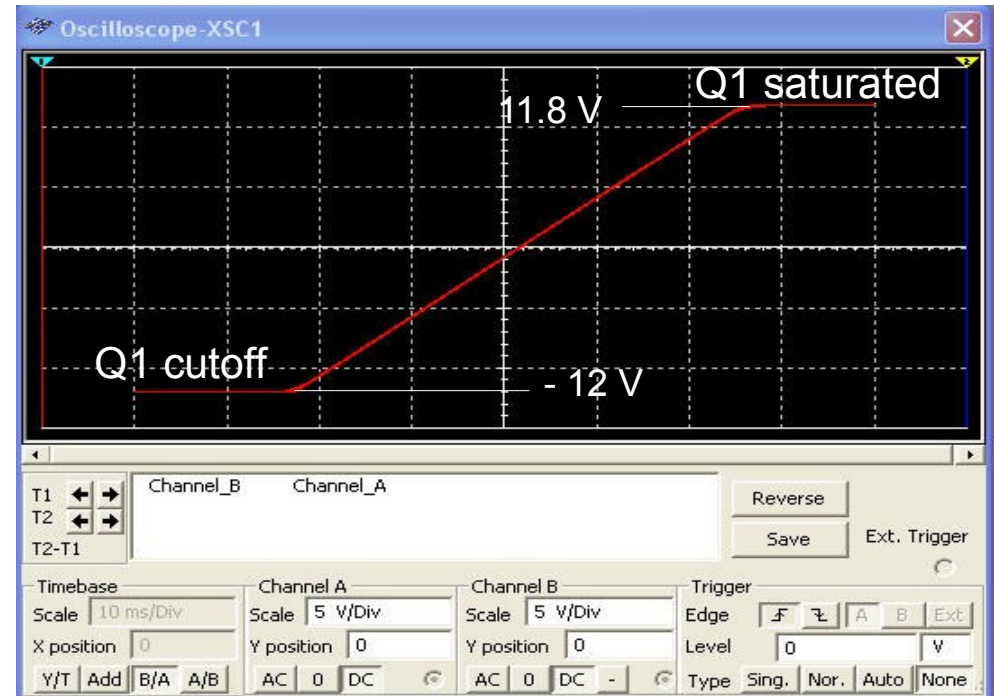
Q1 forward active => no clipping

$$v_O < v_{O-max} = V_{CC} - V_{CE1-sat} = 11.8 \text{ V}$$

$$v_O > v_{O-min} = -IR_L = -12 \text{ V}$$

Q1 not Sat

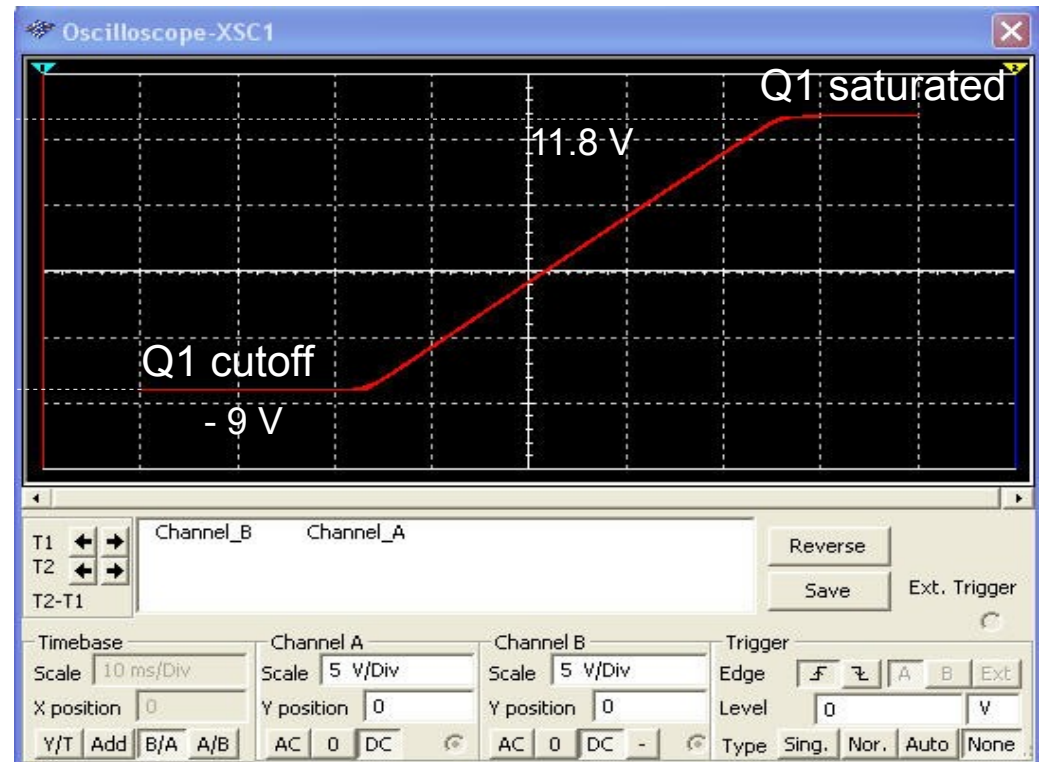
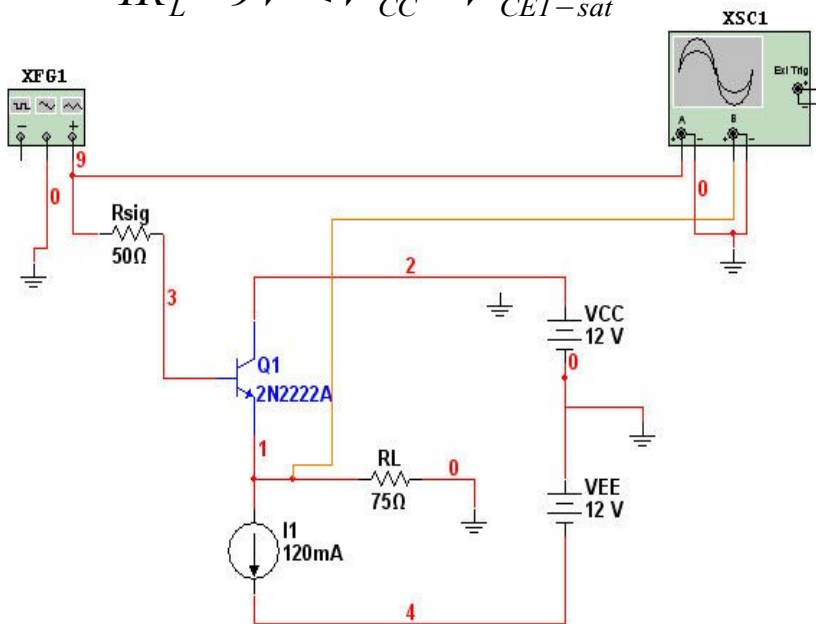
Q1 not Cut-off (there is no Q2)



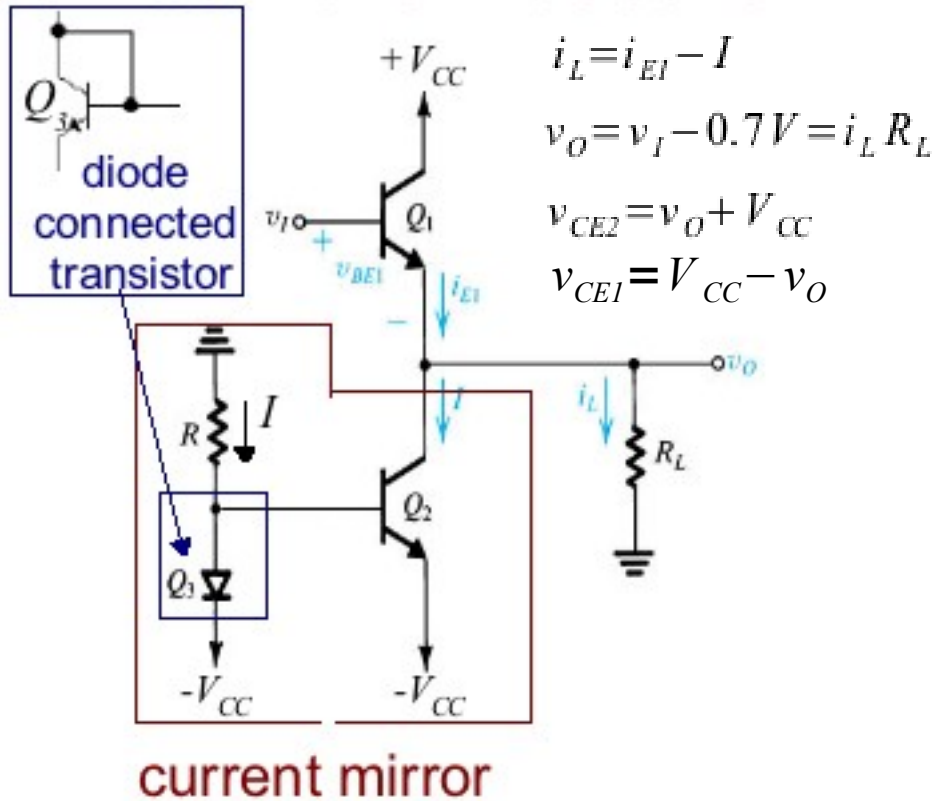
Class A Stage VTC Simulation - cont.

$$I = 120 \text{ mA} \quad R_L = 75 \Omega$$

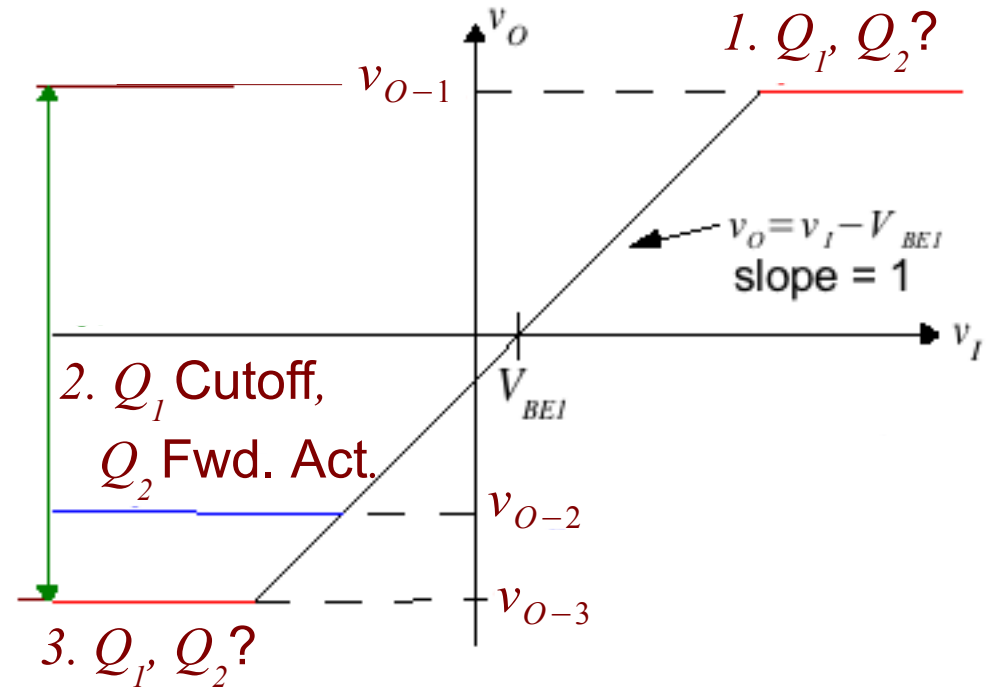
$$IR_L = 9 \text{ V} < V_{CC} - V_{CE1-sat}$$



Quick Review

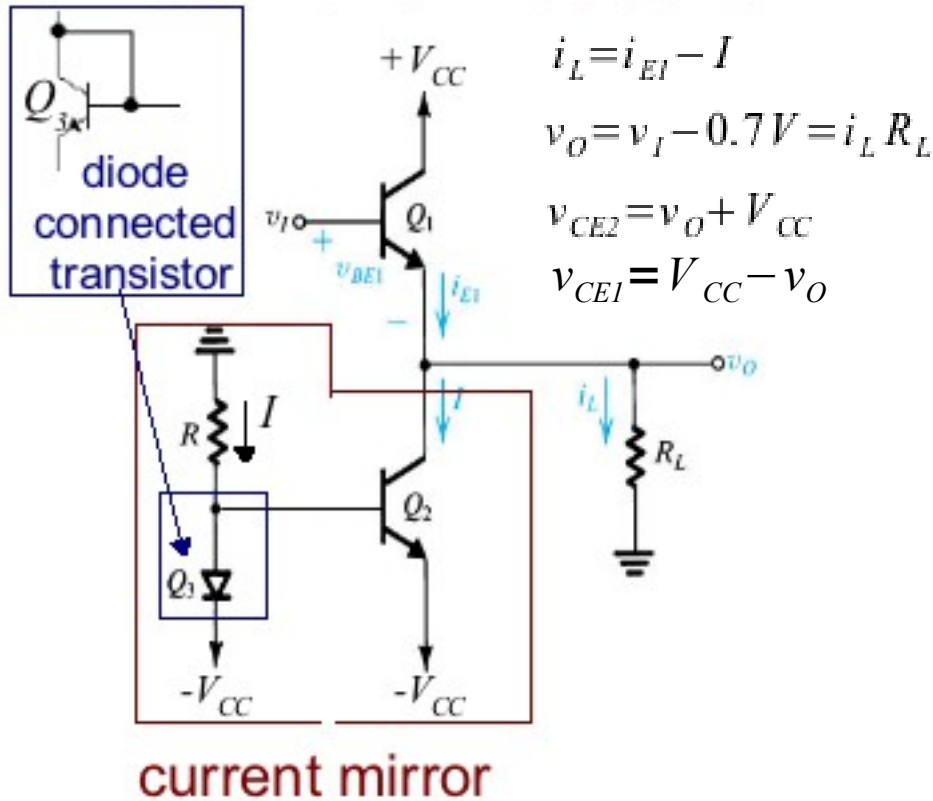


Class A Amp VTC

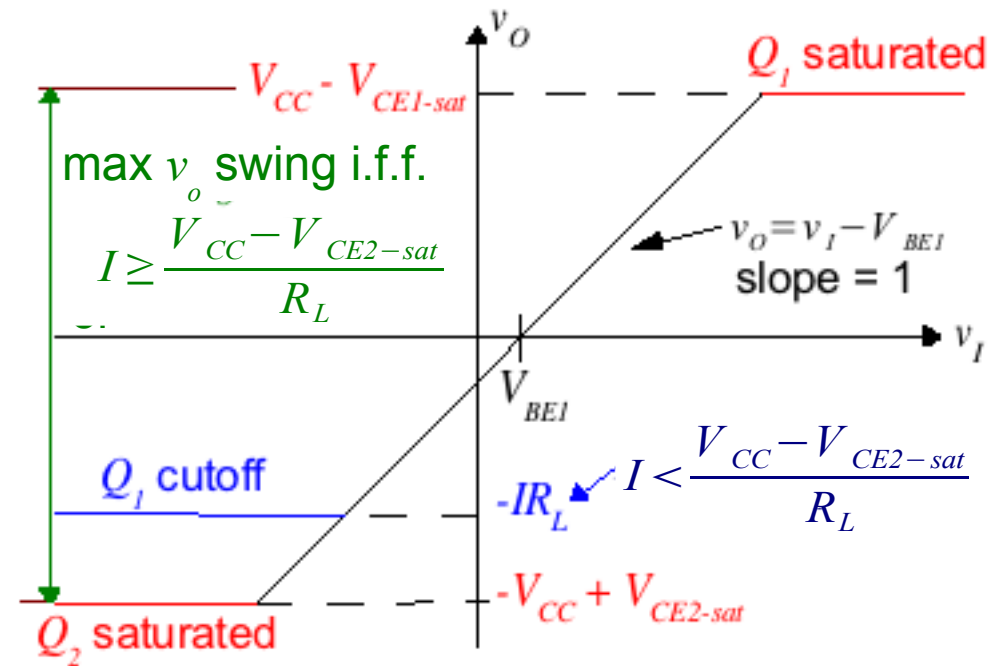


4. Max swing v_O occurs iff

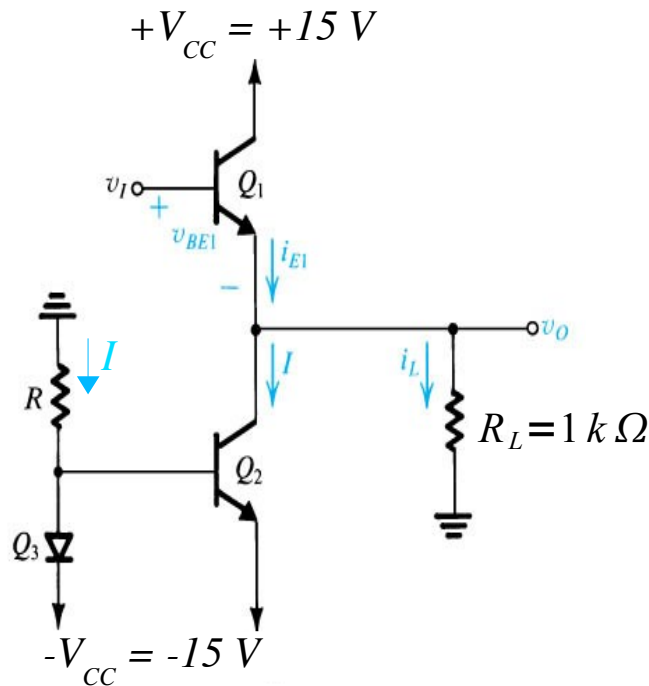
Quick Review



Class A Amp VTC



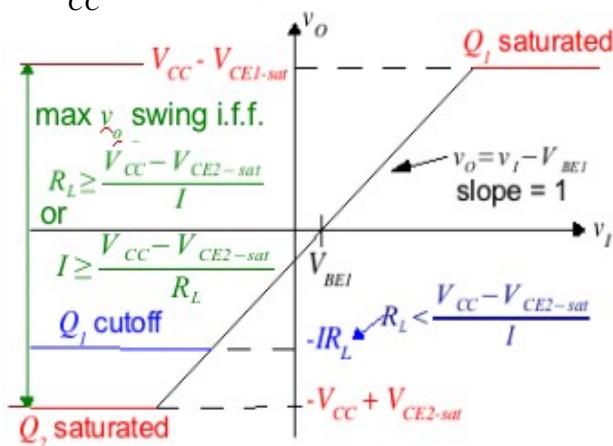
$$v_O = v_I - 0.7 \quad \text{where} \quad \max\{-IR_L, -(V_{CC} - V_{CE2-sat})\} < v_O < V_{CC} - V_{CE1-sat}$$



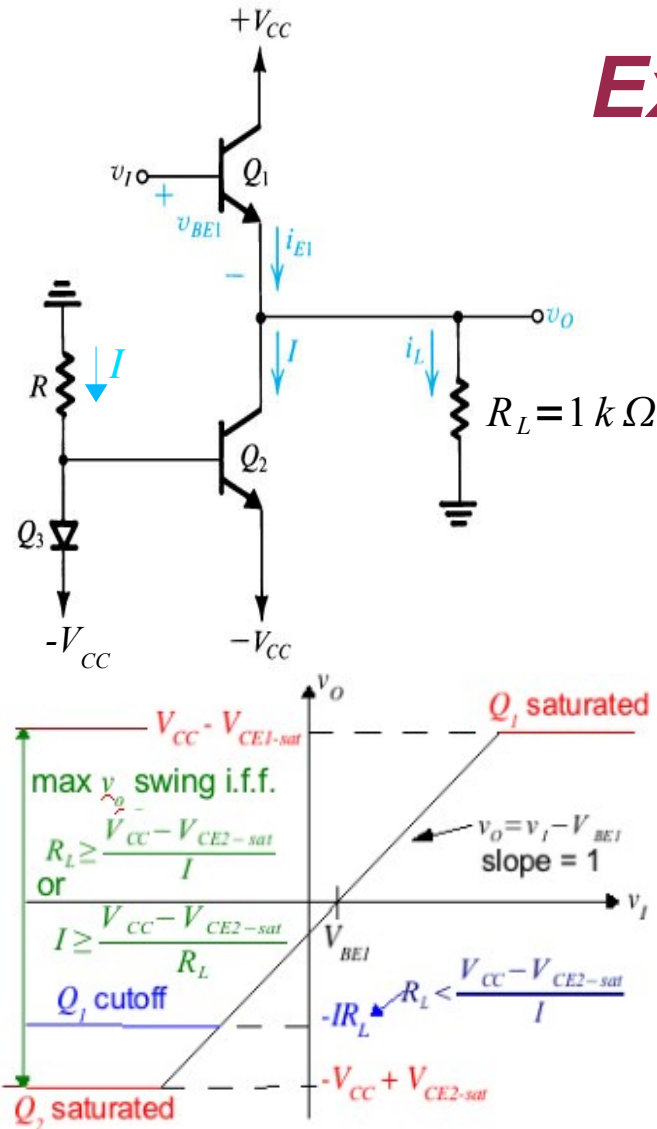
Example

Let $V_{CE1-sat} = V_{CE2-sat} = 0.2\text{ V}$, $V_{BE1} = V_{BE2} = 0.7\text{ V}$ and $\beta_1 = \beta_2 = \text{large}$

1. Determine the value for resistor R that will set the bias current I sufficiently large to allow the **largest possible output voltage v_O swing**.
2. Determine the resulting output voltage swing and the maximum and minimum Q_1 emitter currents.



Example cont.



SOLUTION:

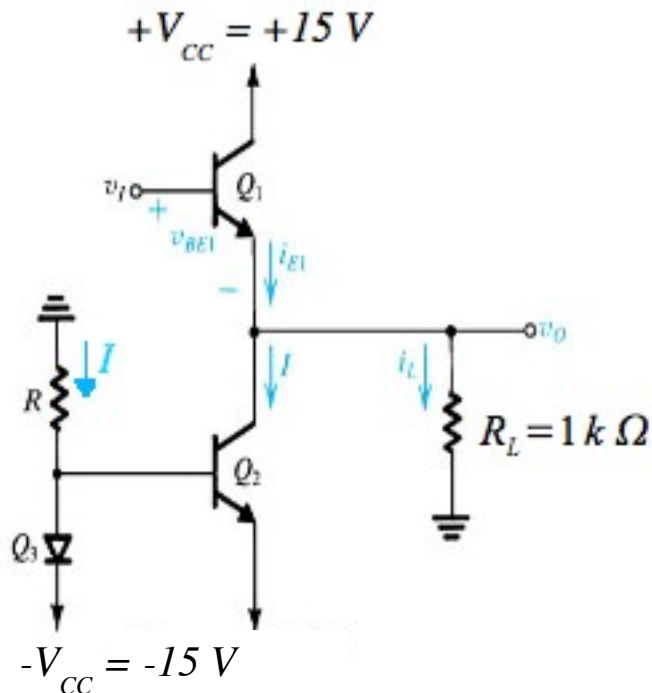
- For maximum output voltage swing:

$$IR_L = V_{CC} - V_{CE2-sat} \quad \text{where } R_L = 1\text{ k}\Omega$$

$$I = \frac{V_{CC} - V_{CEsat}}{R_L} = \frac{15\text{ V} - 0.2\text{ V}}{1\text{ k}\Omega} = 14.8\text{ mA}$$

$$R = \frac{0 - (V_{BE} - V_{CC})}{I} = \frac{15\text{ V} - 0.7\text{ V}}{14.8\text{ mA}} = 0.97\text{ k}\Omega$$

Example - cont.



From Part 1:

$$I = 14.8 \text{ mA}$$

SOLUTION:

2. Output voltage swing:

$$V_{o-peak} = I R_L = 14.8 \text{ V} \Rightarrow -14.8 \text{ V} < v_O < 14.8 \text{ V}$$

$$-14.8 \text{ V} < v_O < 14.8 \text{ V} \Rightarrow -I < i_L < I$$

Max and min Q_1 emitter currents:

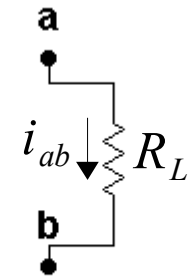
$$i_{E1} = I + i_L \Rightarrow 0 \text{ mA} < i_{E1} < 2I = 29.6 \text{ mA}$$

Instantaneous and Average Power

The source of power to the amplifier load, R_L , comes from the supplies, V_{CC} & $-V_{CC}$. The supplies deliver power, & the load and the transistors absorb it.

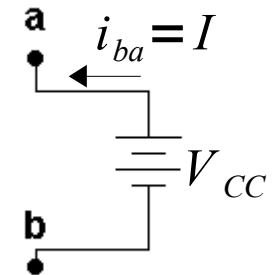
Instantaneous power absorbed by resistor R_L :

$$p_L(t) = v_{ab}(t) i_{ab}(t) = i_{ab}^2(t) R_L = v_{ab}^2(t) / R_L$$



Instantaneous power delivered by battery V_{CC} :

$$p_D(t) = v_{ab}(t) i_{ba}(t) = V_{CC} I$$



Average power: $i_{ab} = I_{ab-peak} \sin(\omega t)$ for period T

$$P_{L av} = \frac{1}{T} \int_0^T i_{ab}^2(t) R_L dt = I_{ab-rms}^2 R_L = \frac{I_{ab-peak}^2}{2} R_L = \frac{V_{ab-peak}^2}{2 R_L}$$

$$P_{D av} = V_{CC} I$$

Power dissipation: $P_{Disp}(V_{ab-peak}) = P_{D av} - P_{L av}$

Emitter Follower Power Relationships

I. Average power delivered by the batteries:

For the current mirror transistor side:

$$P_{-V_{CC}} = V_{CC} I$$

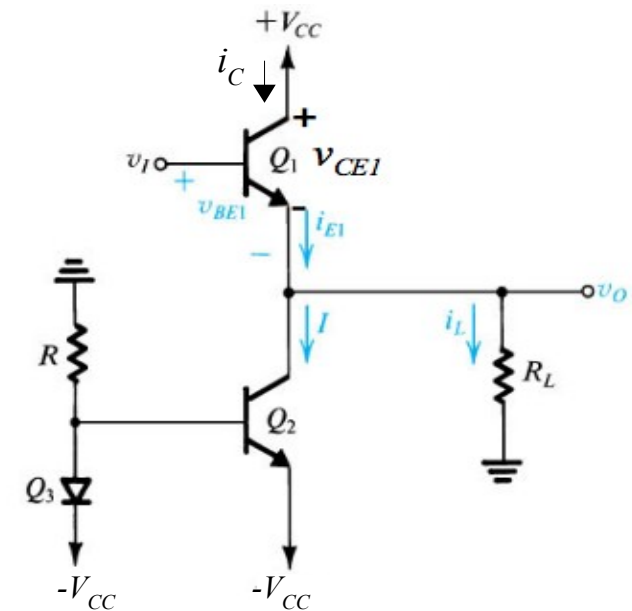
For the amplifier transistor side:

$$P_{+V_{CC}} = \frac{1}{T} \int_0^T V_{CC} i_{C1} dt \quad \text{where} \quad i_{C1} = I + \hat{I}_c \sin(\omega t)$$

$$P_{+V_{CC}} = V_{CC} I \frac{1}{T} \int_0^T \left(1 + \frac{\hat{I}_c}{I} \sin(\omega t)\right) dt = V_{CC} I$$

Total delivered power:

$$P_{D_{av}} = p_D(t) = P_{-V_{CC}} + P_{+V_{CC}} = 2 V_{CC} I$$



II. Average power to the load:

$$v_O = V_{o-peak} \sin(\omega t)$$

$$P_{L_{av}} = \frac{V_{o-rms}^2}{R_L} = \frac{(V_{o-peak} / \sqrt{2})^2}{R_L} = \frac{V_{o-peak}^2}{2 R_L}$$

Class A Power Conversion Efficiency

Using the power delivered to transistors from the batteries $P_{D\text{av}}$ and the power delivered to the load $P_{L\text{av}}$:

$$P_{D\text{av}} = 2V_{CC}I \quad \text{and} \quad P_{L\text{av}} = \frac{V_{o\text{-peak}}^2}{2R_L}$$

Note:

1. Average currents and $P_{D\text{av}}$ from the power supply do not change with the signal level $V_{o\text{-peak}}$.
2. $P_{L\text{av}}$ increases with the square of the signal level $V_{o\text{-peak}}$.

power conversion efficiency

$$\eta = \frac{P_{L\text{av}}}{P_{D\text{av}}} = \frac{V_{o\text{-peak}}^2 / 2R_L}{2V_{CC}I} = \frac{1}{4} \frac{V_{o\text{-peak}}^2}{V_{CC}IR_L} = \frac{1}{4} \frac{V_{o\text{-peak}}}{IR_L} \frac{V_{o\text{-peak}}}{V_{CC}}$$

Power Conversion Efficiency

$$\eta = \frac{1}{4} \frac{V_{o-peak}^2}{I R_L V_{CC}} = \frac{1}{4} \frac{V_{o-peak}}{I R_L} \frac{V_{o-peak}}{V_{CC}}$$

Since $V_{o-peak} < V_{CC}$ and $V_{o-peak} < I R_L$:

Maximum power conversion efficiency is realized when

$$V_{o-peak} = V_{CC} = I R_L \quad \text{ignoring the } V_{CE1-sat} \text{ and } V_{CE2-sat}$$

Hence:

$$\eta_{max} = \frac{1}{4} \frac{V_{CC}}{V_{CC}} \frac{V_{CC}}{V_{CC}} = \frac{1}{4} \quad \text{or } 25 \%$$

and

$$P_{Disp}(V_{o-peak} = 0) = P_{Dav} - P_{Lav} = 2 V_{CC} I$$

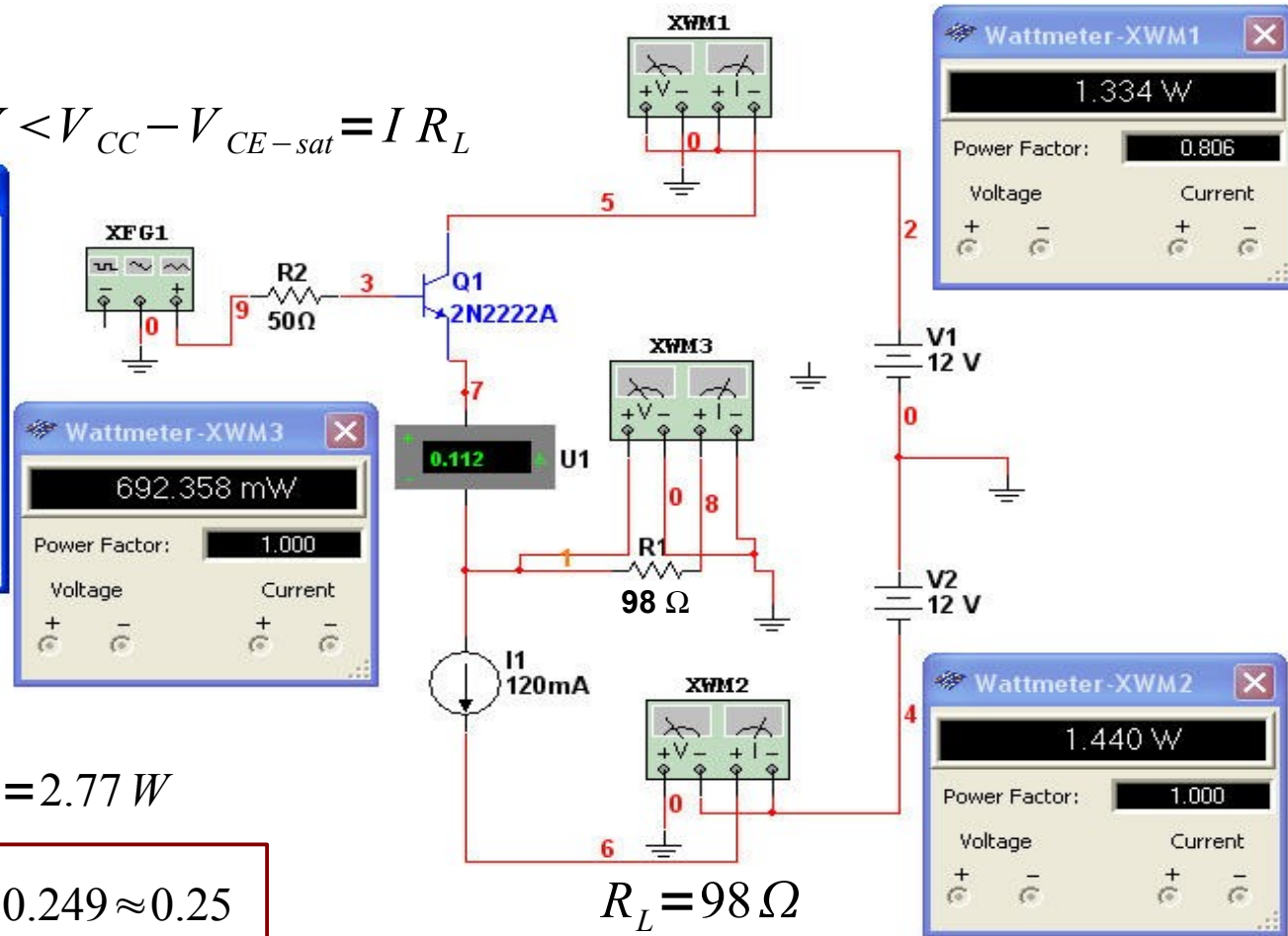
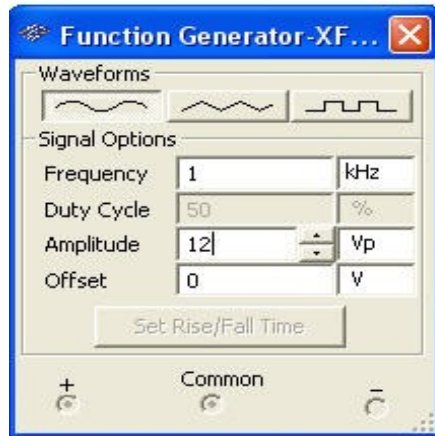
Class A Power Analysis Summary

Power from sources: $\max V_{o-peak} = V_{CC}$	$P_{D_{av}} = 2 V_{CC} I$	$P_{D_{av(max)}} = 2 V_{CC} I$
Power output to load: $\max V_{o-peak} = V_{CC}$	$P_{L_{av}} = \frac{1}{2} \frac{V_{o-peak}^2}{R_L}$	$P_{L_{av(max)}} = \frac{1}{2} \frac{V_{CC}^2}{R_L} = \frac{1}{2} V_{CC} I$
Power Conversion Efficiency:	$\eta = \frac{1}{4} \frac{V_{o-peak}^2}{I R_L V_{CC}}$	$\eta_{max} = \frac{1}{4} = 0.25$
Power dissipation	$P_{Disp} = 2 V_{CC} I - \frac{1}{2} \frac{V_{o-peak}^2}{R_L}$	$P_{Disp(max)} = 2 V_{CC} I$

Class A Power Efficiency Simulation

$$V_{o-peak} = V_{i-peak} - 0.7$$

$$V_{o-peak} = 12 - 0.7 = 11.3 \text{ V} < V_{CC} - V_{CE-sat} = I R_L$$



$$P_{L_{av}} = 692.36 \text{ mW}$$

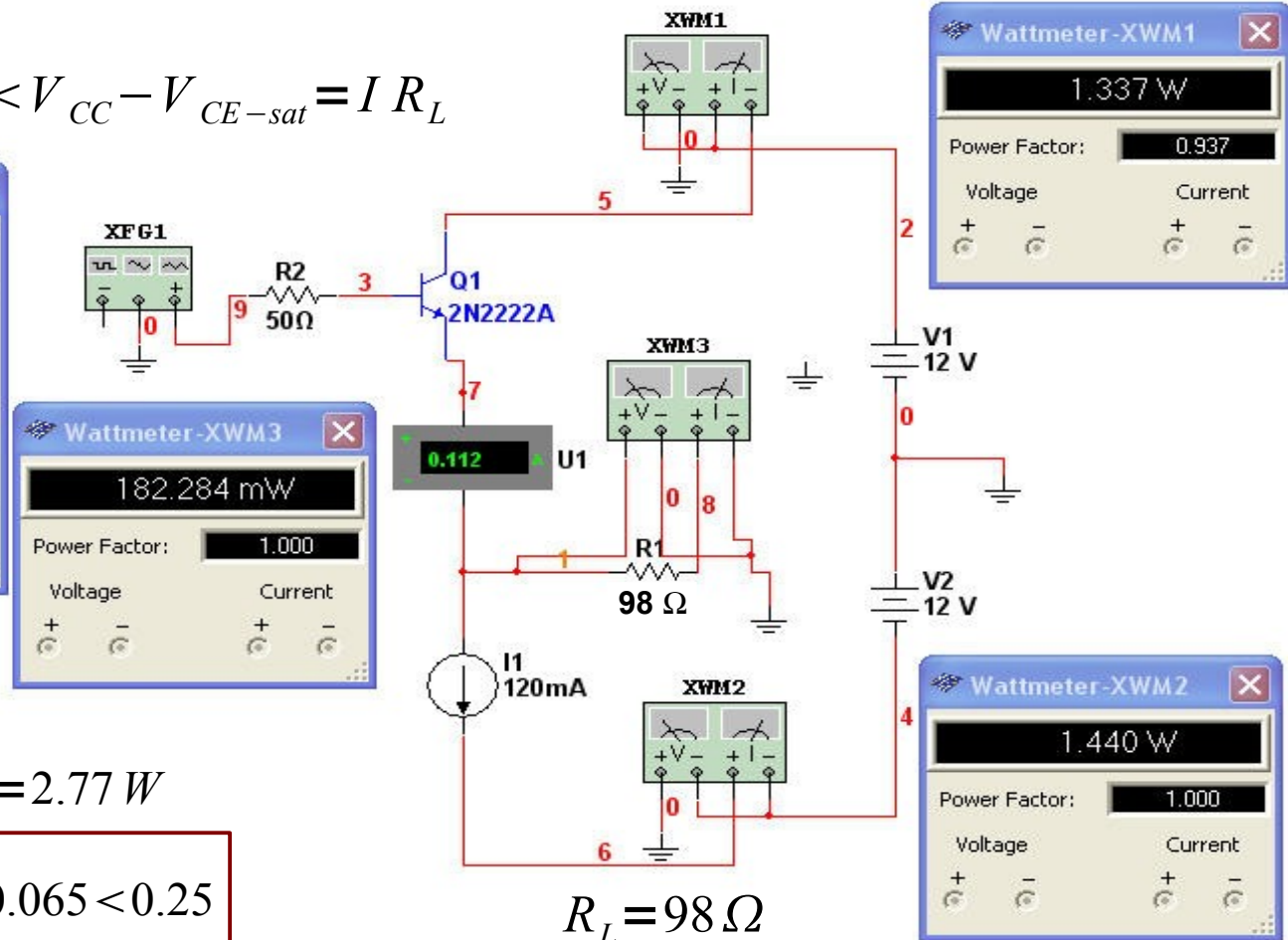
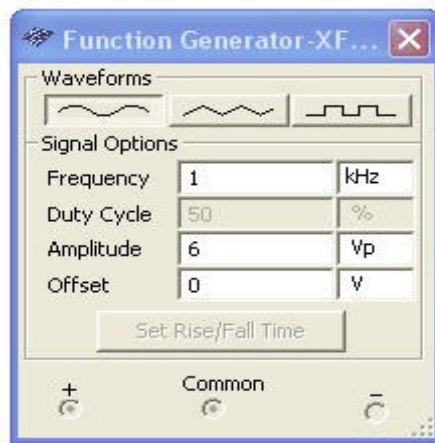
$$P_{D_{av}} = 1.33 \text{ W} + 1.44 \text{ W} = 2.77 \text{ W}$$

$$\eta = \frac{P_{L_{av}}}{P_{D_{av}}} = \frac{0.69 \text{ W}}{2.77 \text{ W}} = 0.249 \approx 0.25$$

Class A Power Simulation - cont.

$$V_{o-peak} = V_{i-peak} - 0.7$$

$$V_{o-peak} = 6 - 0.7 = 5.3 \text{ V} < V_{CC} - V_{CE-sat} = I R_L$$



$$P_{L_{av}} = 182.28 \text{ mW}$$

$$P_{D_{av}} = 1.33 \text{ W} + 1.44 \text{ W} = 2.77 \text{ W}$$

$$\eta = \frac{P_{L_{av}}}{P_{D_{av}}} = \frac{0.18 \text{ W}}{2.77 \text{ W}} = 0.065 < 0.25$$

Conclusions

1. The class A amplifier provides the most “nearly linear” amplification of its input, but this comes at a price: The best power conversion efficiency that can be obtained is 25%.
2. That is 75% of the power supplied by the sources is dissipated in the transistors. This is a waste of power, and it leads to a potentially serious heating problems with the transistors. All of this constant battery power is dissipated in the transistors even when no signal is applied – zero percent efficiency!

Next we will consider a much more efficient amplifier configuration – the class B amplifier.
